PHOTONIC Silicon Photodiode, U.V. Enhanced Photoconductive DETECTORS INC. Type PDU-C109-Q



PACKAGE DIMENSIONS INCH [mm] 0.215 [5.46] Ø0.483 [12.27]-- 0.065 [1.65] WIRE BONDS Ø0.449 [11.39] 1.50 [38.1] Ø0.55 VIEWING 0.295 [7.49] ANODE ANGLE Ø0.018 [0.46] CATHODE Ø0.018 [0.46] -HEADER PHOTODIODE OUARTZ WINDOW CAP (WELDED) 0.340 [8.64] 0.209 [5.31] ACTIVE AREA 0.230 [5.84] TO-8 PACKAGE - 0.319 [8.10] ACTIVE AREA ACTIVE AREA = 42.86 mm²

RESPONSIVITY (A/W)

FEATURES

- High speed
- U.V. enhanced
- Low capacitance
- Quartz window

DESCRIPTION

The **PDU-C109-Q** is a silicon, PIN planar diffused, U.V. enhanced photodiode. Ideal for high speed photoconductive applications. Packaged in a TO-8 metal can with a flat quartz window cap.

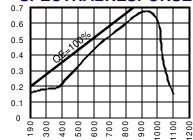
APPLICATIONS

- Spectrometers
- Fluorescent analysers
- U.V. meters
- Colorimeters

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS
VBR	Reverse Voltage		30	V
T _{STG}	Storage Temperature	-55	+150	S
To	Operating Temperature Range	-40	+125	с
Ts	Soldering Temperature*		+240	°C
Ι	Light Current		500	mA

SPECTRALRESPONSE



WAVELENGTH(nm)

*1/16 inch from case for 3 secs max

ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TESTCONDITIONS	MIN	TYP	MAX	UNITS			
lsc	Short Circuit Current	H = 100 fc, 2850 K	450	500		μA			
ΙD	Dark Current	$H = 0, V_{R} = 5 V$		5	15	nA			
Rsh	Shunt Resistance	$H = 0, V_{R} = 10 \text{ mV}$	15	50		MΩ			
TC RSH	RsH Temp. Coefficient	H = 0, V _R = 10 mV		-8		% / °C			
CJ	Junction Capacitance	$H = 0, V_{R} = 5 V^{**}$		475		рF			
λrange	Spectral Application Range	Spot Scan	190		1100	nm			
R	Responsivity	$V_{_{ m R}}$ = 0 V, λ = 254 nm	.12	.18		A/W			
VBR	Breakdown Voltage	I = 10 µLA	15	25		V			
NEP	Noise Equivalent Power	V _R = 10 mV @ Peak		2.5x10 ⁻¹³		W/ / Hz			
tr	Response Time	$RL = 1 K\Omega V_R = 5 V$		150		nS			

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.**f = 1 MHz [FORM NO. 100-PDU-C109-Q REV N/C]